



High-Density Solid-State Memory Devices and Technologies

Guest Editors:

Prof. Dr. Christian Monzio Compagnoni

Dipartimento di Elettronica,
Informazione e Bioingegneria,
Politecnico di Milano, Milan, Italy

Prof. Dr. Riichiro Shiota

Department of Electrical and
Computer Engineering, National
Chiao Tung University, Hsinchu
300, Taiwan

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Message from the Guest Editors

The relevance of solid-state memory technologies in the world of electronics is on the constant rise. Due to their continuously increasing integration density and their unmatched performance, solid-state memory technologies are currently not only gaining importance in the arena of data storage but are also offering the opportunity for new memory-centric computing scenarios. 3-D NAND Flash memory, phase-change memory (PCM), resistive random-access memory (ReRAM), magnetoresistive random-access memory (MRAM), and ferroelectric memory are the most important players at the heart of this memory revolution, along with dynamic random-access memory (DRAM) and static random-access memory (SRAM).





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Editor-in-Chief

Prof. Dr. Flavio Canavero

Department of Electronics and
Telecommunications,
Politecnico di Torino, 10129
Torino, Italy

Message from the Editor-in-Chief

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